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DATA SHEET

CPH6324 — P-Channel Silicon MOSFET

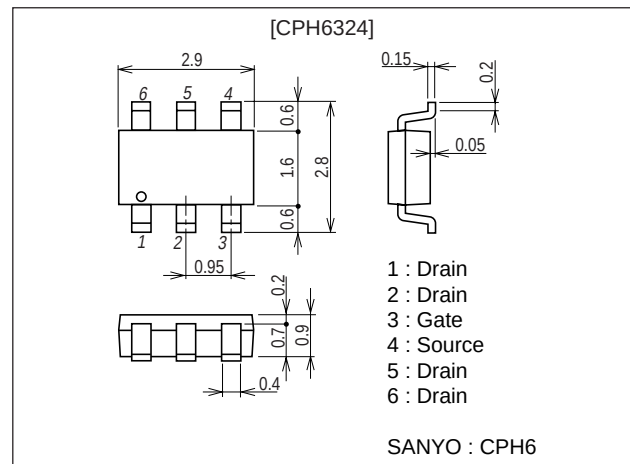
Ultrahigh-Speed Switching Applications

Features

- Low ON-resistance.
- Ultrahigh-speed switching.
- 4V drive.

Package Dimensions

unit : mm
2151A



Specifications

Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	V _{DSS}		-60	V
Gate-to-Source Voltage	V _{GSS}		±20	V
Drain Current (DC)	I _D		-2	A
Drain Current (Pulse)	I _{DP}	PW≤10μs, duty cycle≤1%	-8	A
Allowable Power Dissipation	P _D	Mounted on a ceramic board (1200mm ² ×0.8mm)	1.6	W
Channel Temperature	T _{ch}		150	°C
Storage Temperature	T _{stg}		-55 to +150	°C

Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Drain-to-Source Breakdown Voltage	V _{(BR)DSS}	I _D =-1mA, V _{GS} =0	-60			V
Zero-Gate Voltage Drain Current	I _{DSS}	V _{DS} =-60V, V _{GS} =0			-1	μA
Gate-to-Source Leakage Current	I _{GSS}	V _{GS} =±16V, V _{DS} =0			±10	μA
Cutoff Voltage	V _{GS(off)}	V _{DS} =-10V, I _D =-1mA	-1.2		-2.6	V
Forward Transfer Admittance	y _{fs}	V _{DS} =-10V, I _D =-1A	1.6	2.4		S
Static Drain-to-Source On-State Resistance	R _{DS(on)1}	I _D =-1A, V _{GS} =-10V		275	360	mΩ
	R _{DS(on)2}	I _D =-1A, V _{GS} =-4V		400	560	mΩ

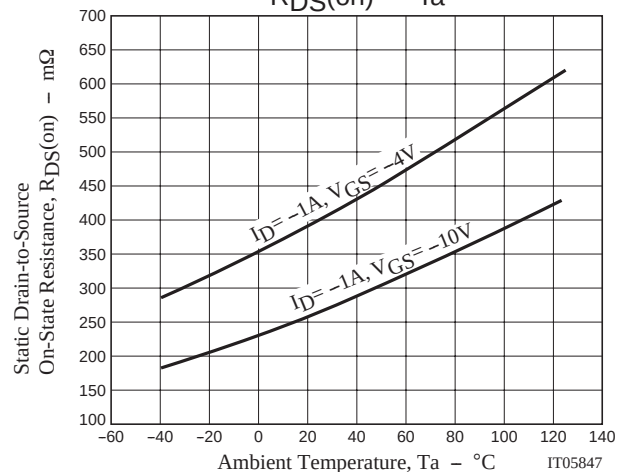
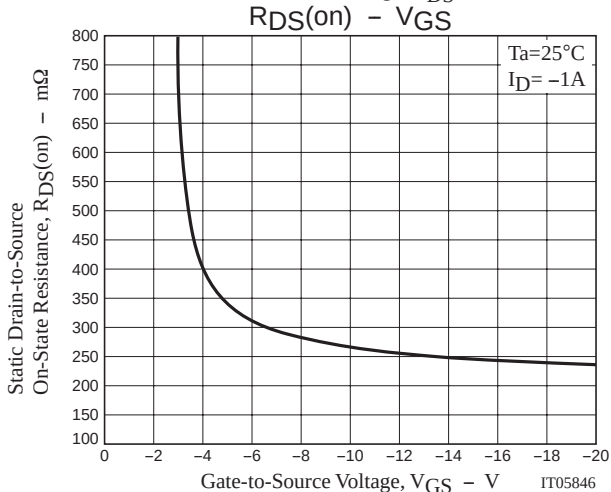
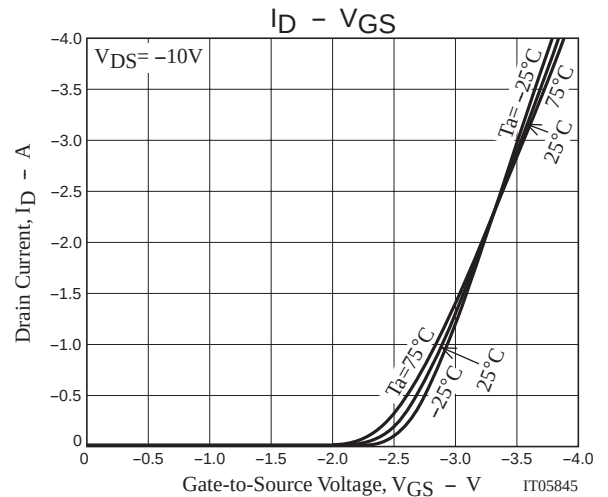
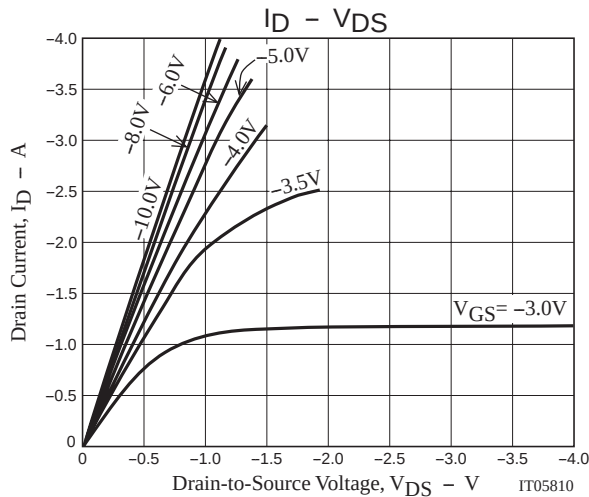
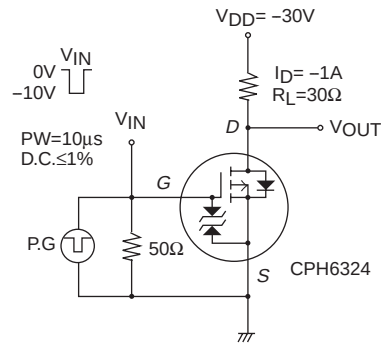
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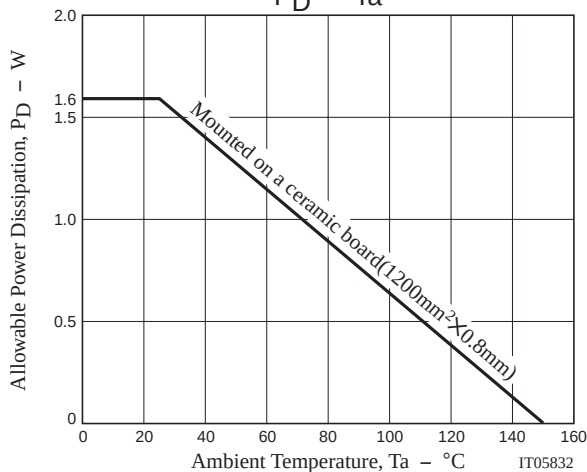
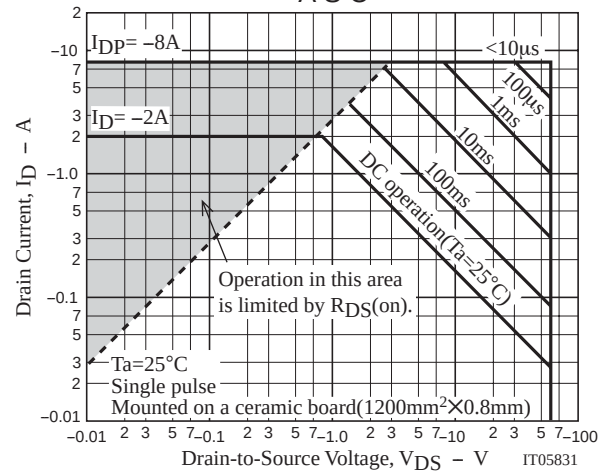
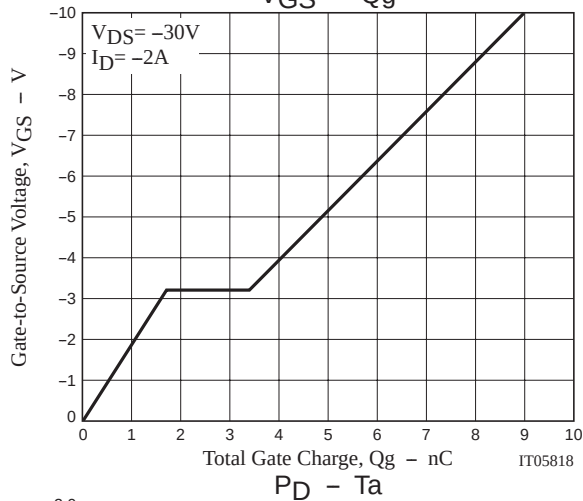
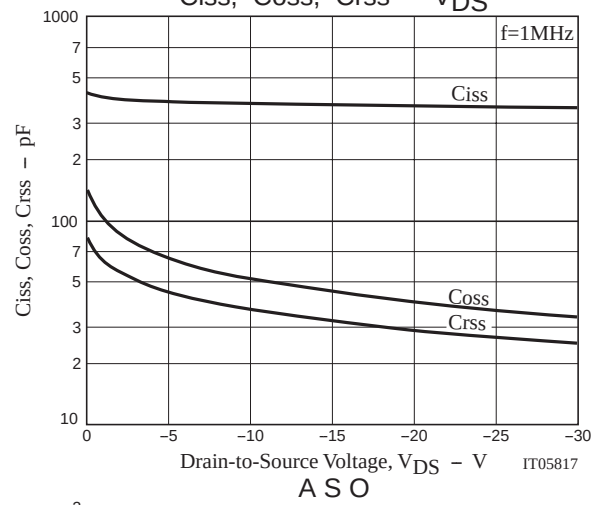
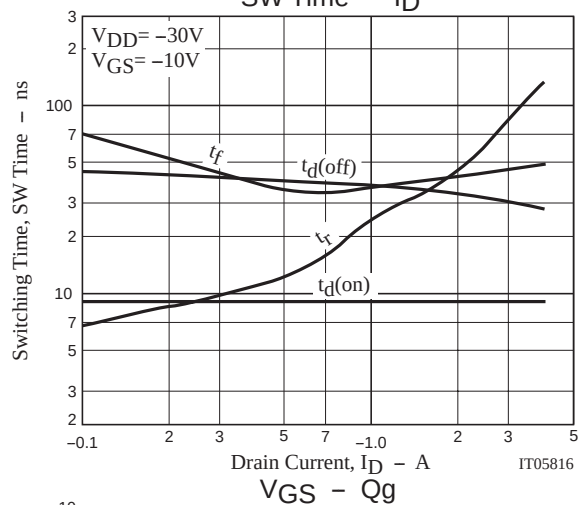
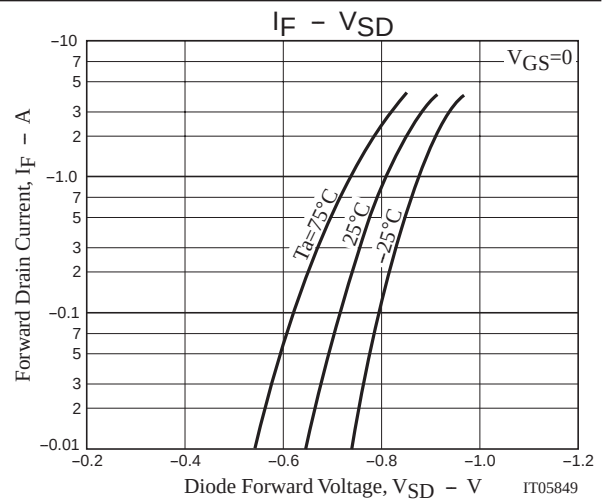
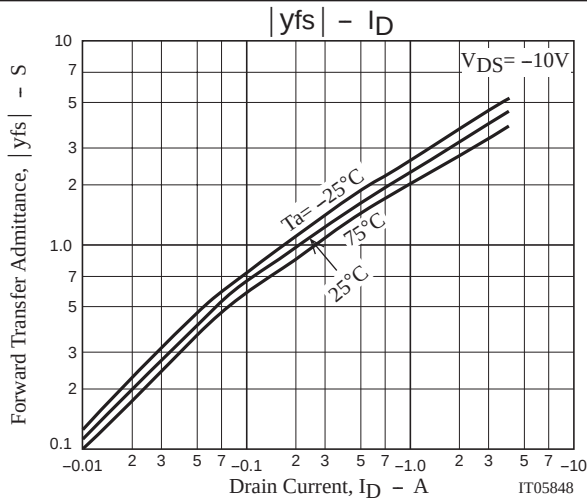
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Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Input Capacitance	Ciss	$V_{DS} = -20V, f = 1MHz$		365		pF
Output Capacitance	Coss	$V_{DS} = -20V, f = 1MHz$		39		pF
Reverse Transfer Capacitance	Crss	$V_{DS} = -20V, f = 1MHz$		30		pF
Turn-ON Delay Time	$t_d(on)$	See specified Test Circuit.		9		ns
Rise Time	t_r	See specified Test Circuit.		24		ns
Turn-OFF Delay Time	$t_d(off)$	See specified Test Circuit.		38		ns
Fall Time	t_f	See specified Test Circuit.		38		ns
Total Gate Charge	Qg	$V_{DS} = -30V, V_{GS} = -10V, I_D = -2A$		9		nC
Gate-to-Source Charge	Qgs	$V_{DS} = -30V, V_{GS} = -10V, I_D = -2A$		1.7		nC
Gate-to-Drain "Miller" Charge	Qgd	$V_{DS} = -30V, V_{GS} = -10V, I_D = -2A$		1.7		nC
Diode Forward Voltage	V_{SD}	$I_S = -2A, V_{GS} = 0$		-0.84	-1.2	V

Switching Time Test Circuit





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